

#### **POWER PIN DIODES**

#### **DESCRIPTION**

These series of PIN diodes are designed for applications requiring small package size and moderate average power handling capability. The low capacitance of the UM6000 and UM6600 allows them to be used as series switching elements to 1 GHz. The low resistance of the UM6200 is useful in applications where forward bias current must be minimized.

Because of its thick I-region width and long lifetime the UM6000 and UM6600 have been used in distortion sensitive and high peak power applications, including receiver protectors, TACN, and IFF equipment. Their low capacitance allows them to be useful as attenuator diodes at frequencies greater than 1 GHz. The UM6200 has been

used successfully in switches in which low insertion loss at low bias current is required. The "A" style package for this series is the smallest Microsemi PIN diode package. It has been used successfully in many microwave applications using coaxial, microstrip, and stripline techniques at frequencies beyond X-Band. The "B" and "E" style leaded packages offer the highest available power dissipation for a package this small. They have been used extensively as series switch elements in microstrip circuits. The "C" style package duplicates the physical outline available in conventional ceramic-metal packages but incorporates the many reliability advantages of the Microsemi construction.

#### **KEY FEATURES**

- Voltage ratings to 1000V
- Average power dissipation to 6 W
- Series resistance as low as 0.4  $\Omega$
- Carrier lifetime greater than 1.0 µs
- Non cavity design
- Thermally matched configuration
- Low capacitance at 0 V bias
- Low conductance at 0 V bias
- Compatible with automatic insertion equipment

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

#### ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED) **Package** Condition UM6000/UM6600 **UM6200** PD PD θ 25 °C Pin Temperature 25 °C/W A & C 6 W 4 W 37.5 °C/W ½ in. total length to 25 °C Contact 60 °C/W 2.0 W 75 °C/W B & E 2.5 W 0.5 W 0.5 W 25 <sup>O</sup>C End Cap Temperature 27.5°C/W SM 4.5 W 3.0 W 42.5 °C/W UM6000 25 kW ΑII 1 us pulse (Single) 10 kW UM6600 13 kW

VOLTAGE RATINGS							
Reverse Voltage @ 10 uA		_					
100	UM6001	UM6201	UM6601				
200	UM6002	UM6202	UM6602				
400	-	UM6204	-				
800	UM6006	-	UM6606				
1000	UM6010	-	UM6610				

#### APPLICATIONS/BENEFITS

- Isolated stud package available
- Surface mount package available
- RoHS compliant packaging available: use UMX6001B, etc.



#### **POWER PIN DIODES**

ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)								
Parameter	Symbol	Conditions	UM6600	UM6000	UM6200	Units		
Reverse Current (Max)	$I_{R}$	At rated voltage	10	10	10	uA		
Series Resistance(Max)	Rs	If = 100 mA, F= 100 MHz	2.5	1.7	0.4	Ohms		
Capacitance (Max)	Ст	$V_R = 100 \text{ V}, F = 1 \text{ MH}_Z$	0.4	0.5	1.1	pF		
Parallel Resistance(Min	) Rp	$V_R = 100 \text{ V}, F = 100 \text{ MHz}$	300k	300k	350k	Ohms		
Carrier Lifetime(Min)	τ	I <sub>F</sub> = 10 mA	1.0	1.0	0.6	us		
I-Region Width (Min)	W	-	150	150	40	um		

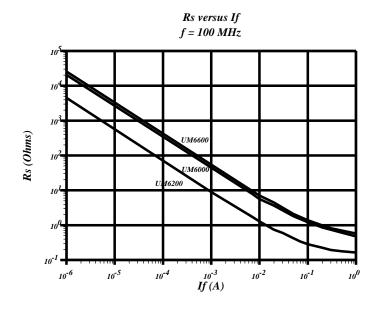




Style "B"

Style "SM"

#### UM6000/UM6200/UM6600



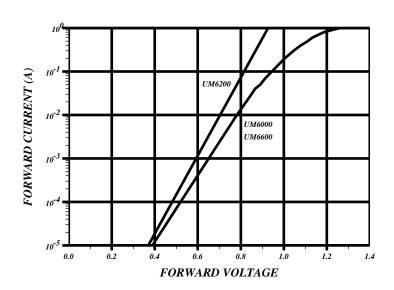
Copyright © 2005 Rev. 0, 2013-02-28



### **POWER PIN DIODES**

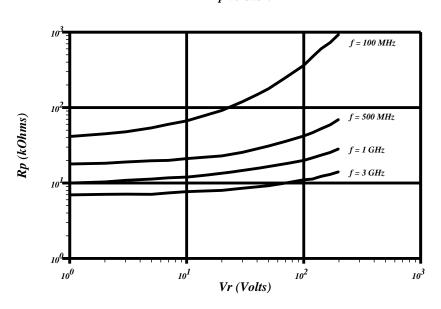
#### UM6000/UM6200/UM6600

FORWARD VOLTAGE versus CURRENT



#### UM6000/UM6600

#### Rp versus Vr

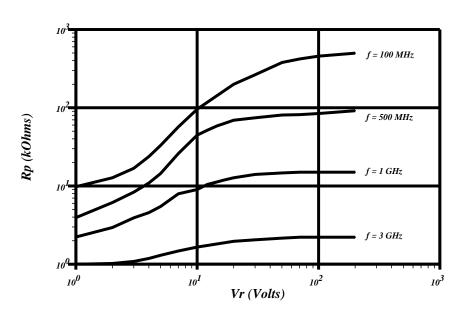




#### **POWER PIN DIODES**

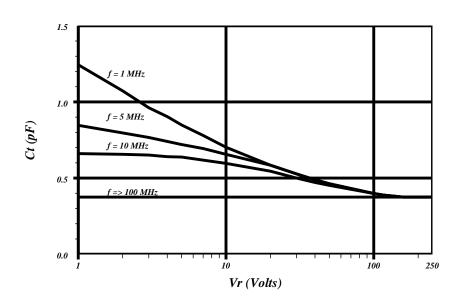
#### **UM6200**

Rp versus Vr



#### **UM6000**

#### Ct versus Vr

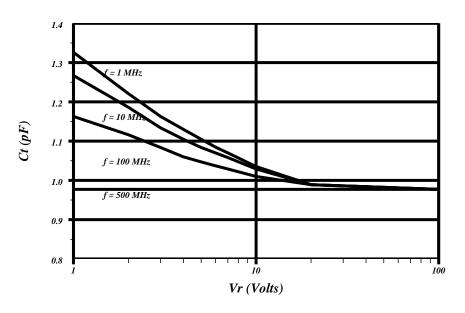




#### **POWER PIN DIODES**

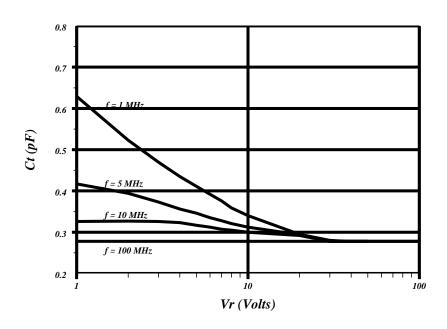
#### **UM6200**

#### Ct versus Vr



### **UM6600**

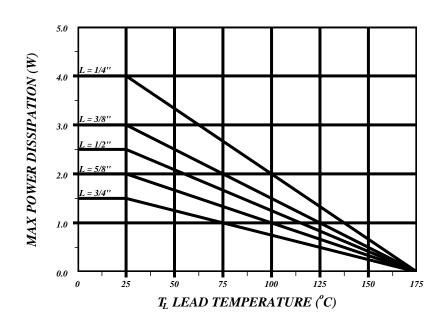
#### Ct versus Vr





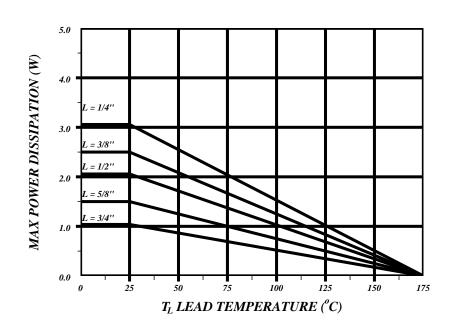
#### **POWER PIN DIODES**

## UM6000/UM6200 MAX POWER DISSIPATION versus LEAD TEMPERATURE



UM6600

MAX POWER DISSIPATION versus LEAD TEMPERATURE

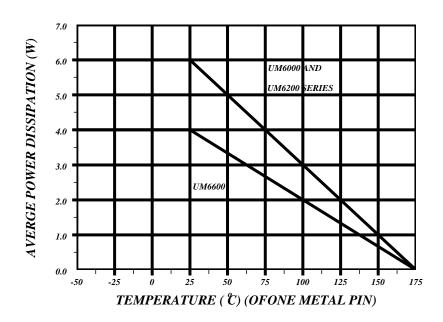




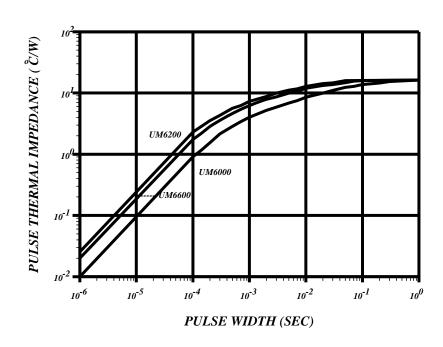
#### **POWER PIN DIODES**

#### UM6000/UM6200/UM6600

#### **AVERGE POWER DISSIPATION versus TEMPERATURE**



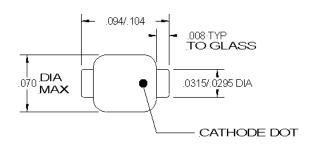
# UM6000/UM6200/UM6600 PULSE THERMAL IMPEDANCE VS PULSE WIDTH



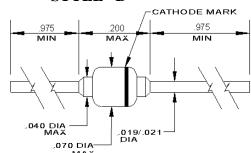


### **POWER PIN DIODES**

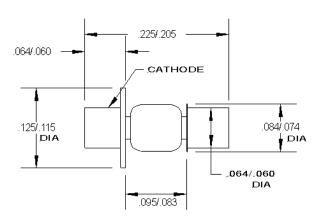
#### STYLE "A"



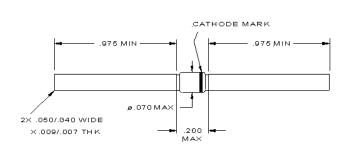
#### STYLE "B"



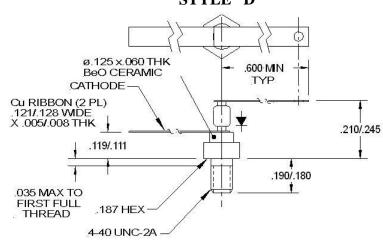
#### STYLE "C"



#### STYLE "E"



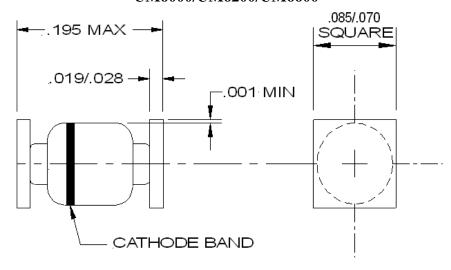
#### STYLE "D"



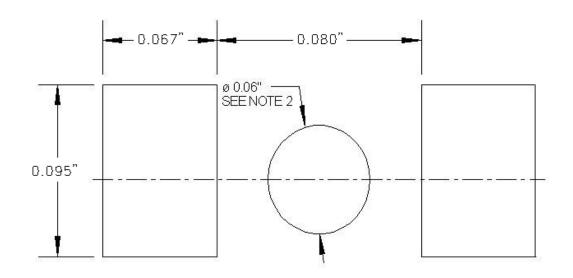


**POWER PIN DIODES** 

#### UM6000/UM6200/UM6600



#### UM6000/UM6200/UM6600 STYLE "SM" FOOTPRINT





#### **POWER PIN DIODES**

#### NOTES:

- 1. These dimensions will match the terminals and provide for additional solder fillets at the outboard ends at least as wide as the terminals themselves, assuming accuracy of placement within 0.005"
- 2. If the mounting method chosen requires use of an adhesive separate from the solder compound, a round (or square) spot of cement as shown should be centrally located.

NOTES:

Copyright © 2005 Rev. 0, 2013-02-28

## **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

## Microchip:

<u>UM6002SM UM6606SM UM6001A UM6001B UM6002B UM6010E UM6601B UM6204E UM6610B UM6202B UMX6002SM UMX6202SM UM6606A UMX6001B UM6201B UM6201A UMX6602SM UM6010A</u>